# **IOTOROLA**Freescale Semiconductor, Inc.

Semiconductor Technical Data

## Preliminary

# **Automotive Dual High Side Driver**

This device called "Flasher Lite" is a dual high side power switch dedicated for automotive applications. In comparison with mechanical relays, this device offers higher reliability as well as protection and diagnostic features.

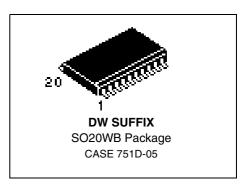
The device consists of two independent  $25m\Omega$  Rdson switches in a surface mount package. It can be directly interfaced with a microcontroller for control and diagnostic functions and includes a current recopy function. The device is fully protected against overcurrents, short-circuits and incorporates an overtemperature shutdown. It can be directly and continuously supplied by the battery and offers a very low quiescent current in standby mode.

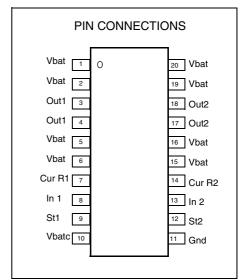
- Designed for Automotive Applications
- Junction Temperature Range from 40°C to 150°C
- Operating Voltage Range from 8V to 40V
- Reverse Battery protected up to -14V with no external components
- Surface Mount Package, Thermally Enhanced
- 25mOhms max Rdson per Channel at 25°C
- Independant Status Lines, one per channel
- Overtemperature Protection with Hysteresis
- Open Load Detection in On-State
- Short-Circuit Protection
- · Loss of gnd, loss of Vbat protection
- Independant Current Recopy, one per channel
- Under Voltage Shutdown
- ESD Protection 2kV
- Current Limitation greater than 25A to Allow load Inrush Current
- Standby Current less than 1uA at V<sub>bat</sub> =14V and ambiant temperature

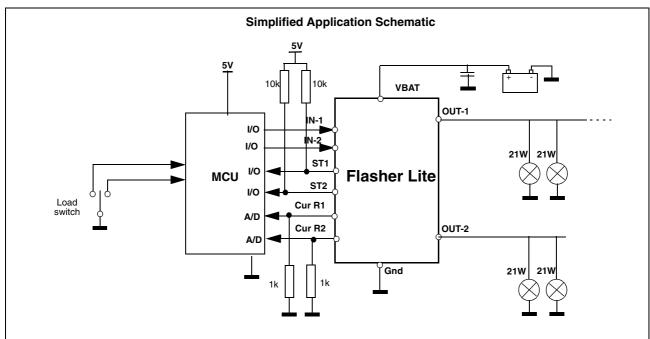
### XC33487

Order Number: XC33487/D

Rev. 1.3, 06/2001







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Ratings	Symbol	Value	Unit		
ELECTRICAL RATINGS					
Vbat Voltage with Respect to Gnd : Continuous/Pulse	Vbat	-14 to + 40	V		
Out-1 & Out-2 Voltage with Respect of Gnd : Continuous/Pulse	Vout	-0.3 to 40	V		
Out-1 to Vbat & Out-2 to Vbat voltage : Continuous/Pulse	Vout	40	V		
IN-1, IN-2, ST-1, ST-2 Voltage : Continuous/Pulse	Vin	-0.3 to 7	V		
Cur R1, Cur R2 Voltage : Continuous/Pulse	Vcr	-0.3 to 7	V		
ESD all Pins	Vesd	+/-2000	V		
Out-1, Out-2 DC Output Current	loutdc	8	Amp		
Out-1, Out-2 Output Current : Pulse	loutp	40	Amp		
IN-1, IN-2, ST-1, ST-2, Cur R1, Cur R2 Input Current	lin	+/-5	mA		

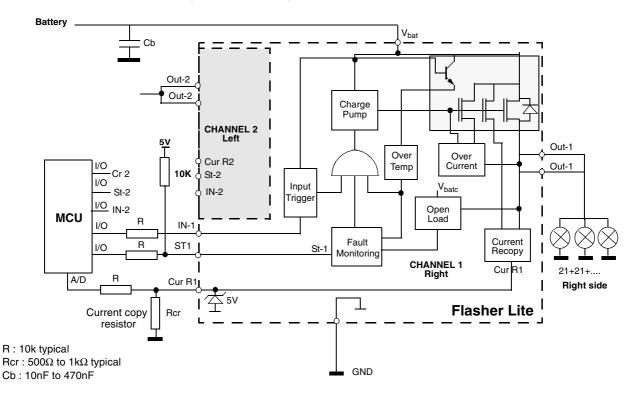
### THERMAL RATINGS

Junction Temperature	Tj	- 40 to 150	°C
Storage Temperature Range	Tst	- 65 to +150	°C
Thermal Resistance Junction to Case	Rthjc	12	°C/W
Thermal Resistance Junction to Ambient (note 1)	Rthja	60	°C/W
Power Dissipation at Tcase 105°C (note 2)	Pd	3.75	W

- NOTES:

  1. Device mounted with minimum pcb dimensions.
- 2. Assuming a 150°C maximum junction temperature.

Figure 1. Block Diagram and Application Schematic





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LLLCTRICAL CHARACTERISTICS (Vbatc and Vbatp from 9 to 16 V and junction temperature Tj from -40° to 150°C, unless otherwise noted)

Description	Symbol	Characteristics			Unit	Conditions	
Description	Symbol	min.	typ.	max.	Oiiit	Conditions	
Nominal Operating Voltage	V <sub>bat</sub>	9		16	V		
Functional Operating Voltage	V <sub>bat</sub>	8		35	٧		
Under Voltage Threshold	V <sub>uv</sub>	6	7	8	V		
Vbat Standby Supply Current	I <sub>stdby</sub>			1		$V_{bat}$ <14V & $V_{in}$ = 0V, $T_j$ = 25°C	
Vbat Standby Supply Current	I <sub>stdby</sub>			25	μА	$V_{bat}$ <14V & $V_{in}$ = 0V, $T_j$ = 125°C	
Supply Current in On State	I <sub>on</sub>		8	20	mA	IN-1 & IN-2 @3.5V, no fault, Vbat<14V	
Drain to Source on Resistance	R <sub>dson</sub>		17	22	mΩ	lout =4A,T <sub>j</sub> = 25°C	
Drain to Source on Resistance	R <sub>dson</sub>		22	30	mΩ	lout = 4A, T <sub>j</sub> = 125°C	
High Current Limitation	I <sub>lim</sub>		30		Α	Vout>1V	
Short Circuit Limitation	I <sub>lim</sub>		10			Vout<1V	
Hot Openload Threshold	I <sub>ol</sub>		0.6		Α		
Output Body Diode Voltage	V <sub>bd</sub>		0.7		٧	lout = -4A, Tj = 25°C	
Reverse Battery Drain to Source Voltage	V <sub>rb</sub>			200	mV	lout = -4A, Vbat = -14V, Tj = 125°C	
Vbat to Output Breakdown Voltage	V <sub>dss</sub>	40			V	In-1 and In-2 @ 0V, Vout = 0, lout -0.25mA	
Vbat to Out : Leakage Current	I <sub>out-leak</sub>			10	μА	Vin =0V, Vbat =40V, Vout=0V	
Vin-1, Vin-2 : Input Voltage Low Threshold	V <sub>il</sub>			1.5	V		
Vin-1, Vin-2: Input Voltage High Threshold	V <sub>ih</sub>	3.5			V		
Vin-1, Vin-2: Input Voltage Hysteresis	V <sub>ih</sub>	0.2	0.7	0.9	V		
Vin-1, Vin-2: Input Current	l <sub>in</sub>		18	30	μА	Vin-1, Vin-2 = 3.5V	
Status Output Voltage	Vst			0.5	V	Ist = 1mA; Output in Fault	
Thermal Shutdown	T <sub>shut</sub>	150			°C		
Thermal Shutdown Hysteresis	T <sub>hyst</sub>		10		°C		
Current Recopy Ratio	Cr		1/1000			Vout>Vbat -1V, lout from 2A to 4A Tj -40°C to 125°C, Vbat 9 to 16V	
Current Recopy Ratio Accuracy	Cr-ac	-10		10	%	Vout >Vbat -1V, lout from 2A to 4A Tj -40°C to 125°C, Vbat 9 to 16V	
Current Recopy Clamp Voltage At 10mA	Vclst	5.5		7	V	lout=9A	
Frequency Operation	Fop			150	Hz		
Maximum Output Positive Slew Rate	Tr	0.01	0.2	0.5	V/μs		
Maximum Output Negative Slew Rate	Tf	0.15	0.5	1.5	V/μs		
Turn On delay time	Tdon		50	150	μs	load = $6\Omega$ , from Vin/2 to10% Vout	
Turn Off delay time	Tdoff		70	150	μs	load = 6 $\Omega$ , from Vin/2 to 90% Vout	



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### **FUNCTIONAL TRUTH TABLE**

Conditions	IN1	IN2	OUT1	OUT2	St1	St2
Normal Operation	L	L	L	L	Н	Н
	Н	L	Н	L	Н	Н
	L	Н	L	Н	Н	Н
	Н	Н	Н	Н	Н	Н
Undervoltage	Х	Х	L	L	Н	Н
Overtemperature Channel 1	Н	Х	L	Х	L	Н
Overtemperature Channel 2	X	Н	X	L	Н	L
Overtemperature Channel 1/Channel 2	Н	Н	L	L	L	L
Open Load Channel 1	Н	Х	Н	Х	L	Н
Open Load Channel 2	X	Н	Х	Н	Н	L
Overcurrent Channel 1	Н	Х	Х	Х	Н	Н
Overcurrent Channel 2	X	Н	Х	Х	Н	Н

### **PIN FUNCTION DESCRIPTION**

Pin No.	Name/Function	Description
1, 2, 5, 6, 15, 16, 19, 20	V <sub>bat</sub> Supply Voltage  V <sub>batc</sub> Supply Voltag	These are the power supply pins of the device. These pins are directly connected with the lead frame of the package and are tied to the drain of the switching MOSFET. These pins can be directly connected to the battery voltage. In addition to their supply functions, these pins participate to the thermal behaviour of the device in conducting the heat from the switching MOSFET to the printed circuit board. V <sub>batc</sub> provide the supply voltage to the control die.
3, 4, 18, 17	OUT1 OUTPUT Channel 1 OUT 2 OUTPUT Channel 2	Pins 3 and 4 are the output 1 terminals. Pins 17 and 18 are the output 2 terminals. They are directly connected to the source of the power MOSFET. The Rdson is $25 m\Omega$ max per output at $25^{\circ}\text{C}$ . Its value increases up to $40 m\Omega$ at $150^{\circ}\text{C}$ junction temperature.
8, 13	IN 1 INPUT Channel 1 IN 2 INPUT Channel 2	These are the device input pins, which directly control their associated output. The thresholds are CMOS compatible. When the input is in low state, the associated output MOSFET is off. When input is high, the MOSFET is turned on and the load is activated. When both inputs are low, the device is in standby mode and its supply current is less than 10uA for V <sub>bat</sub> up to 14V.
7, 14	Cur R1 Current Recopy for Channel 1 Cur R2 Current Recopy for Channel 2	These pins corresponds to a current recopy for each outputs. Their high accuracy permit to allow a precise monitoring of the outputs loads as well as to detect a failed lamp among several lamps.  An external resistor must be connected to these pins which can be tied to a microcontroller A/D for analog measurements
9, 12	ST-1 Status for Channel 1 ST-2 Status for Channel 2	These pins are the channel 1 and 2 status. Their internal structure is an open drain with an internal clamp at 6V. An external pull up connected to the 5V is needed. When the device is in normal condition the status is high. If open load or overtemperature occurs on one channel, the associated output status will be pulled low.





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